

**1 Watt/2 Watt S-Band Power Amplifier
2.2 - 2.4 GHz**

**AM42-0055
V1**

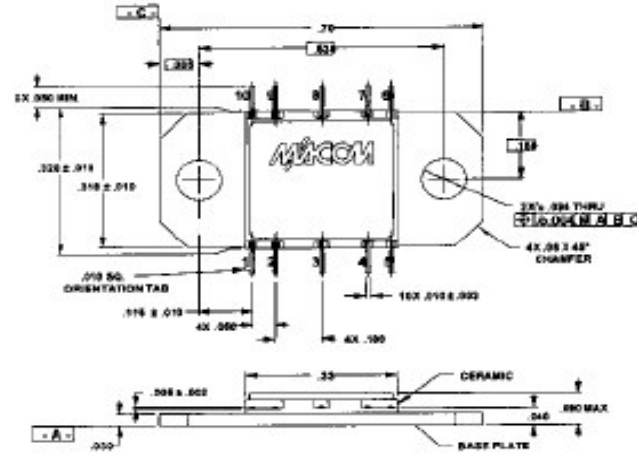
Features

- High Linear Gain: 29 dB typ.
- High Saturated Output Power: +33 dBm typ.
- 50 Ohm Input/Output Broadband Matched

Description

M/A-COM's AM42-0055 is a two stage MMIC power amplifier in a bolt down ceramic package, allowing easy assembly. The AM42-0055 employs a fully matched chip with internally decoupled gate and drain bias networks. The AM42-0055 is designed to operate from a constant current drain supply or a constant voltage gate supply. By varying the bias conditions, the saturated output power performance of this device may be tailored for various applications. The AM42-0055 is ideally suited for use as an output stage in telemetry systems. The AM42-0055 includes internal supply line bypassing in the package, minimizing the number of external components required. M/A-COM's AM42-0055 is fabricated using a mature 0.5-micron MBE based GaAs MESFET process. The process features full passivation for increased performance and reliability. This product is 100% RF tested to ensure compliance to performance specifications.

Outline Drawing ¹



Notes: (Unless Otherwise Specified)
1. Dimensions are in inches.
2. Tolerance: in .xxx = ± .005
.xx = ± .010

1. Die available upon request (die size = 2970 x 2550 μm).

Electrical Specifications: , V_{DD} = +5V/+8V, V_{GG} adjusted for I_{ds} = 800 mA (with RF), Z₀ = 50Ω, T_A = 25°C

Parameter	Test Conditions	Frequency	Units	V _{DD} = +5 V (1 W operation)	V _{DD} = +8 V (2 W operation)
Linear Gain	Pin = -10 dBm, I _{ds} = 800 mA typ.	2.2 - 2.4 GHz	dB	25 typ.	25 typ.
Input VSWR	Pin = -10 dBm	2.2 - 2.4 GHz	Ratio	<2.0:1	<2.0:1
Output VSWR	Pin = -10 dBm	2.2 - 2.4 GHz	Ratio	<2.0:1	<2.0:1
Saturated Output Power	Pin = +10 dBm	2.2 - 2.4 GHz	dBm	30 typ.	33 typ.
Output Power vs. Frequency	Pin = +10 dBm	2.2 - 2.4 GHz	dBm	±0.9 typ.	±0.4 typ.
Drain Bias Current	Pin = +100 dBm	2.2 - 2.4 GHz	mA	700 typ.	800 typ.
Gate Bias Voltage (V _{GG})	Pin = +10 dBm	2.2 - 2.4 GHz	V	-2.0 min; -0.4 max	-2.0 min; -0.4 max
Gate Bias Current (I _{GG})	Pin = +10 dBm	2.2 - 2.4 GHz	mA	25 typ.	25 typ.
Power Added Efficiency	Pin = +100 dBm	2.2 - 2.4 GHz	%	30 typ.	29 typ.

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Absolute Maximum Ratings ^{2,3,4,5,6}

Parameter	Absolute Maximum
Input Power	+ 12 dBm
V _{DD}	+ 10 Volts
V _{GG}	-5 Volts
V _{DD} -V _{GG}	12 Volts
I _{ds}	1200 mA
Channel Temperature	+150°C
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C

2. Operation of this device outside any of these limits may cause permanent damage.
3. Adequate heat sinking and grounding required on flange base.
4. Apply -3 volts to pins 5 and 6 (V_{GG}), prior to applying +8 volts to pins 1 pr 10 (V_{DD}). Adjust V_{GG} for typical drain current.
5. For optimum IP₃ performance, the V_{DD} bypass capacitors should be placed within 0.5 inches of the V_{DD} leads.
6. DC blocks are required for RF input and output ports.

Pin Configuration

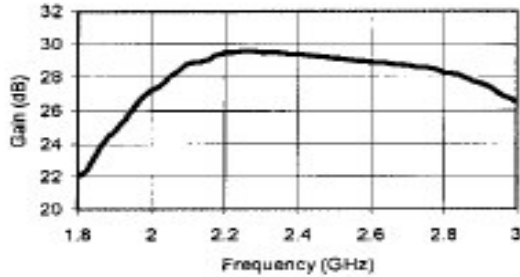
Pin No.	Pin Name	Description
1	VD1	Drain Supply to First Stage
2	GND	RF and DC Ground
3	RF IN	RF Input
4	GND	RF and DC Ground
5	VG1	Gate Supply to First Stage
6	VG2	Gate Supply to Second Stage
7	GND	RF and DC Ground
8	RF OUT	RF Output
9	GND	RF and DC Ground
10	VD2	Drain Supply to Second Stage

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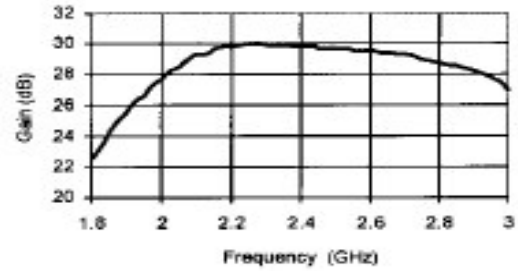
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Typical Performance Curves

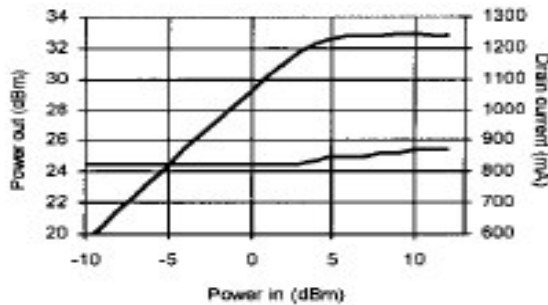
**2 WATT PERFORMANCE
LINEAR GAIN VS FREQUENCY**



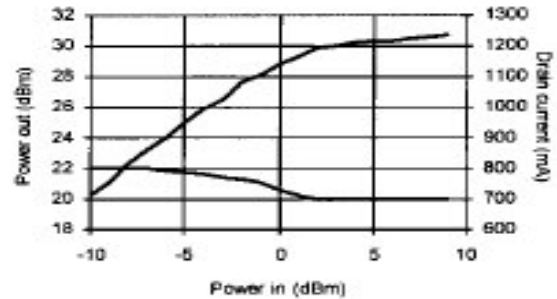
**1 WATT PERFORMANCE
LINEAR GAIN VS FREQUENCY**



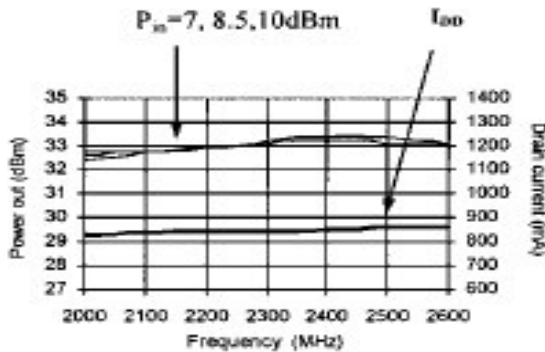
**2 WATT PERFORMANCE
 P_{OUT} AND CURRENT VS P_{IN}**



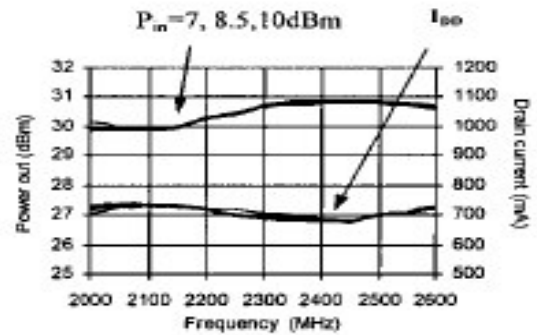
**1 WATT PERFORMANCE
 P_{OUT} AND CURRENT VS P_{IN}**



**2 WATT PERFORMANCE
GAIN AND CURRENT VS FREQ.**



**1 WATT PERFORMANCE
GAIN AND CURRENT VS FREQ.**

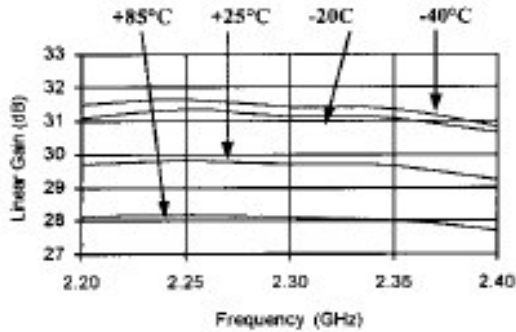


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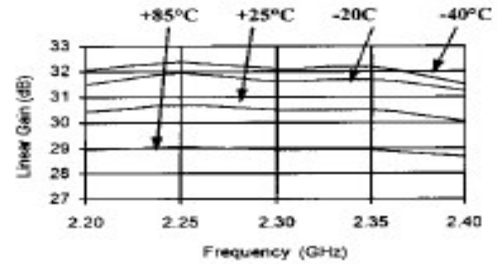
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Typical Performance Curves

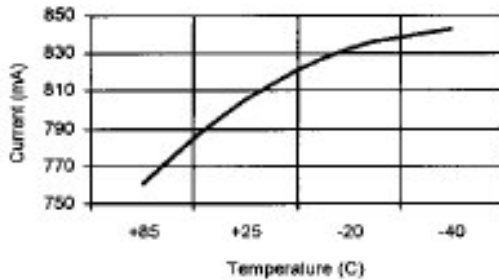
**2 WATT PERFORMANCE
LINEAR GAIN VS FREQ AND TEMP**



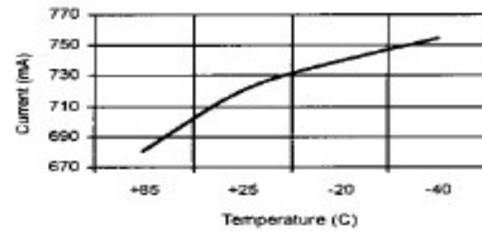
**1 WATT PERFORMANCE
LINEAR GAIN VS FREQUENCY**



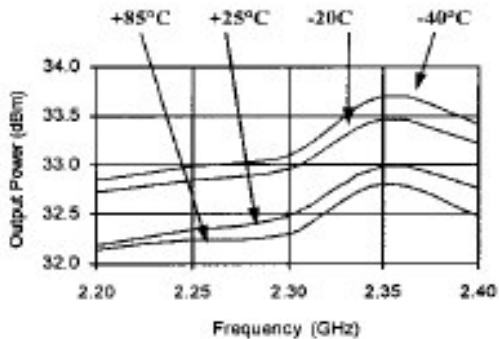
**2 WATT PERFORMANCE
CURRENT VS TEMP AT 1.5 GHz**



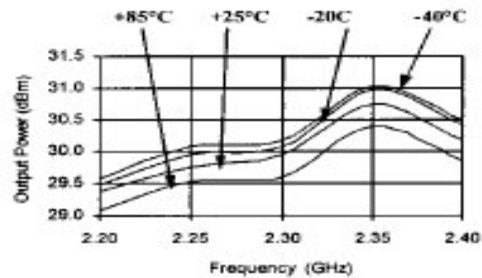
**1 WATT PERFORMANCE
CURRENT VS TEMP AT 1.5 GHz**



**2 WATT PERFORMANCE
P_{out} VS FREQ AND TEMP**



**1 WATT PERFORMANCE
P_{out} VS FREQ AND TEMP**



Ordering Information ⁷

Part Number	Package
AM42-0055	CR-15 Package

7. Die available upon request.